



POWERING
CUSTOMER
INNOVATION

Micron Technology, Inc.



Ivan Donaldson

Director of Investor Relations



Safe Harbor

During the course of this meeting, we may make projections or other forward-looking statements regarding future events or the future financial performance of the Company and the industry. We wish to caution you that such statements are predictions and that actual events or results may differ materially. We refer you to the documents we file on a consolidated basis from time to time with Securities and Exchange Commission, specifically our most recent Form 10-K and Form 10-Q. These documents contain and identify important factors that could cause our actual results on a consolidated basis to differ materially from those contained in our projections or forward-looking statements. These certain factors can be found at <http://investors.micron.com/riskFactors.cfm>. Although we believe that the expectations reflected in the forward-looking statements are reasonable, we cannot guarantee future results, levels of activity, performance or achievements. We are under no duty to update any of the forward-looking statements after the date of the presentation to conform these statements to actual results.

Long Term Memory Market Conditions

Consolidated Suppliers

- Suppliers with sufficient scale
- Return-focused investment and supply environment

Low Supply Growth

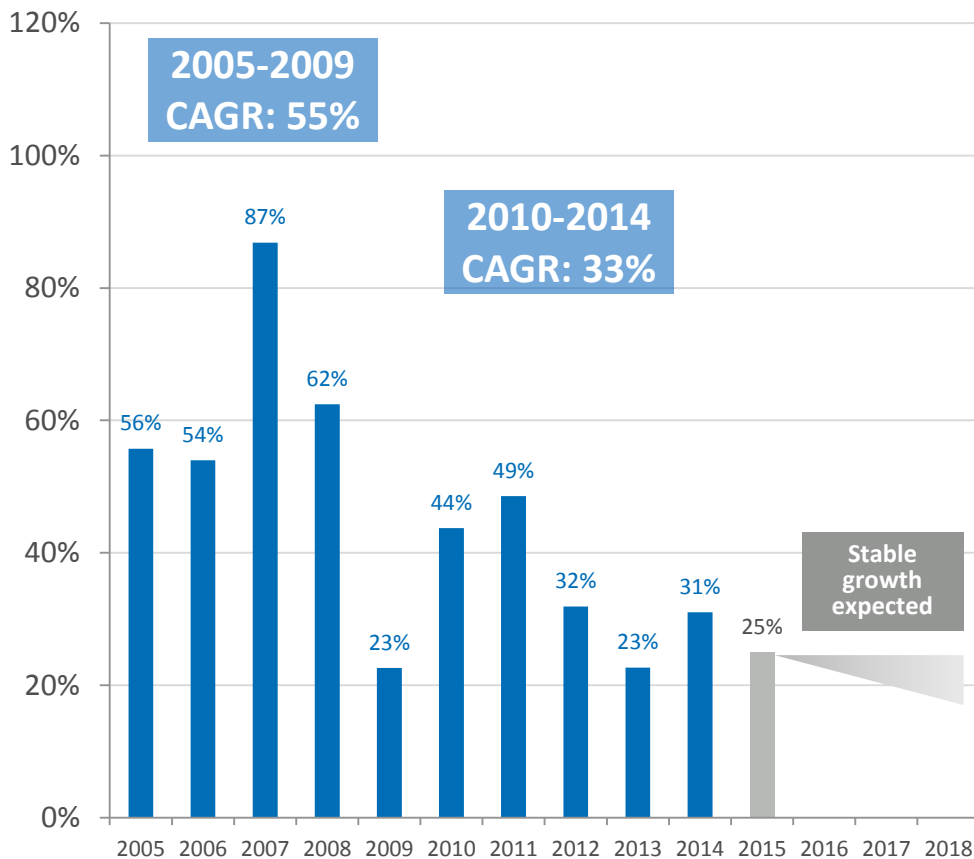
- Limited new wafer capacity
- Slowing technology migrations

Diversifying Demand

- Differentiated products
- System solutions
- Diversified customers
- Broadening applications

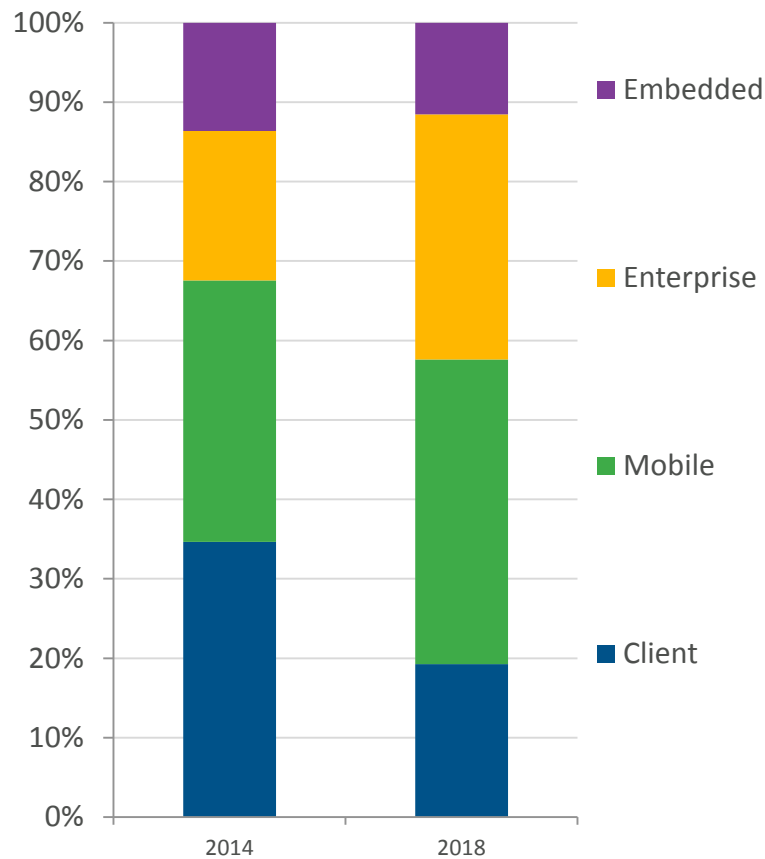
DRAM Supply Growth Slowing, Continued Shift to Mobile and Enterprise Segments

DRAM Industry Y/Y Bit Shipment Growth



Major suppliers: 6 in 2005 down to 3 today

DRAM Industry Bit Demand Profile



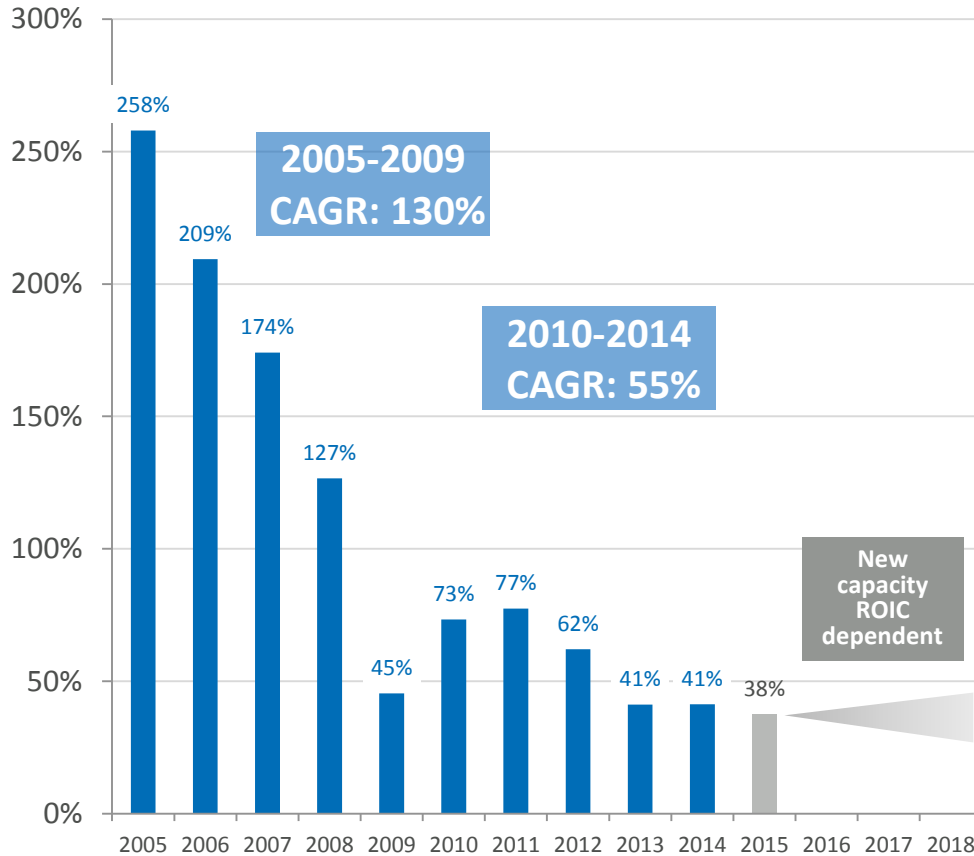
Embedded: AIMM, Consumer, Connected Home
 Enterprise: Server (Enterprise and Cloud), Networking
 Mobile: Handsets, Tablets
 Client: PC, Graphics

Source: Micron and Industry Analysts



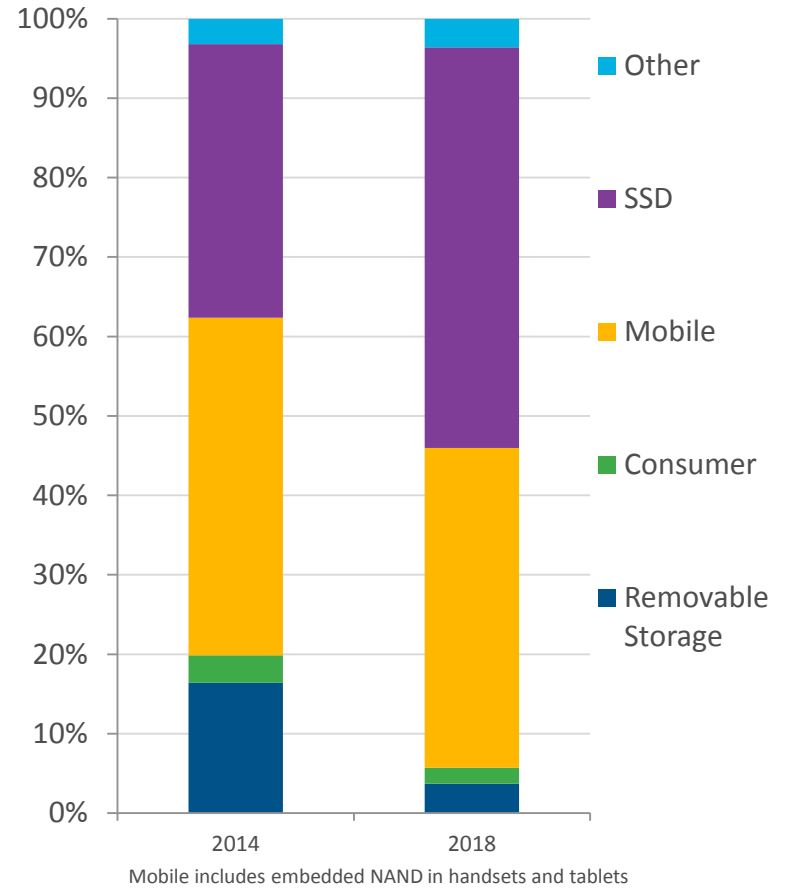
NAND Supply Growth Slowing, Further Increase in SSD Demand

NAND Industry Y/Y Bit Shipment Growth



4 major NAND suppliers today

NAND Industry Bit Demand Profile



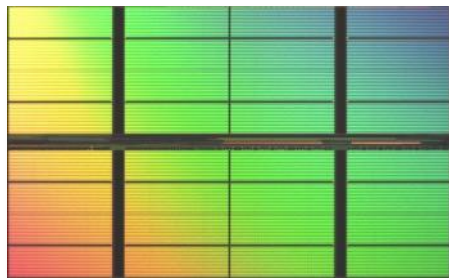
Source: Micron and Industry Analysts



Next Generations of DRAM: 20nm and 1Xnm

Combined DRAM R&D Team Reaping Benefits

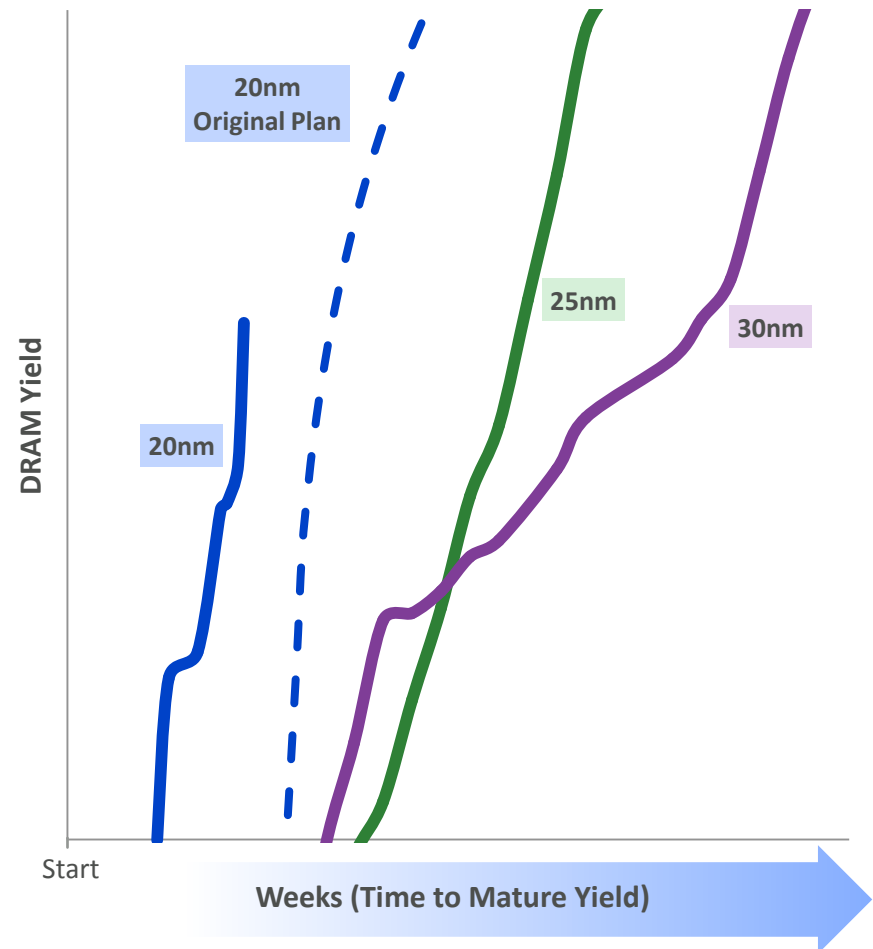
- Hiroshima R&D in manufacturing fab ensures knowledge share between manufacturing and R&D, enabling more rapid yield ramp
- Dedicated R&D operation in Boise enables more revolutionary DRAM R&D without impacting manufacturing
- Focus on enabling scaling path to sub-15nm DRAM



1Xnm DRAM

1Xnm driving >30% improvement in cost per Gb over 20nm

Yield Ramps Improving



Micron 3D NAND

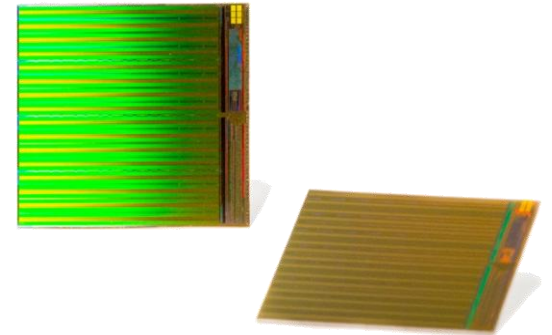
A Disruptive Storage Architecture

CAPACITY	Enables the highest-density flash device ever developed
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COST	Architected to achieve better cost efficiency than 2D NAND
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CONFIDENCE	3D architecture increases performance and endurance
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256 Gb MLC	384 Gb TLC
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Technology Deployment

